

# HD74LVC240A

# Octal Buffers / Line Drivers with 3-state Outputs

REJ03D0351-0400Z (Previous ADE-205-109B (Z)) Rev.4.00 Jul. 26, 2004

## **Description**

The HD74LVC240A has eight inverter drivers with three state outputs in a 20 pin package. This device is an inverting buffer and has two active low enables ( $1\overline{G}$  and  $2\overline{G}$ ). Each enable independently controls four buffers. Low voltage and high-speed operation is suitable at the battery drive product (note type personal computer) and low power consumption extends the life of a battery for long time operation.

#### **Features**

- $V_{CC} = 2.0 \text{ V to } 5.5 \text{ V}$
- All inputs  $V_{IH}$  (Max.) = 5.5 V (@ $V_{CC}$  = 0 V to 5.5 V)
- All outputs  $V_{OUT}$  (Max.) = 5.5 V (@ $V_{CC}$  = 0 V or output off state)
- Typical  $V_{OL}$  ground bounce < 0.8 V (@ $V_{CC}$  = 3.3 V, Ta = 25°C)
- Typical  $V_{OH}$  undershoot > 2.0 V (@ $V_{CC}$  = 3.3 V, Ta = 25°C)
- High output current  $\pm 24$  mA (@V<sub>CC</sub> = 3.0 V to 5.5 V)
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)		
HD74LVC240AFPEL	SOP-20 pin (JEITA)	FP-20DAV	FP	EL (2,000 pcs/reel)		
HD74LVC240ATELL	TSSOP-20 pin	TTP-20DAV	Т	ELL (2,000 pcs/reel)		

Note: Please consult the sales office for the above package availability.

#### **Function Table**

In	nı	ıte
m	μι	เเธ

G	A	Output \( \overline{\text{Y}} \)
Н	X	Z
L	Н	L
L	L	Н

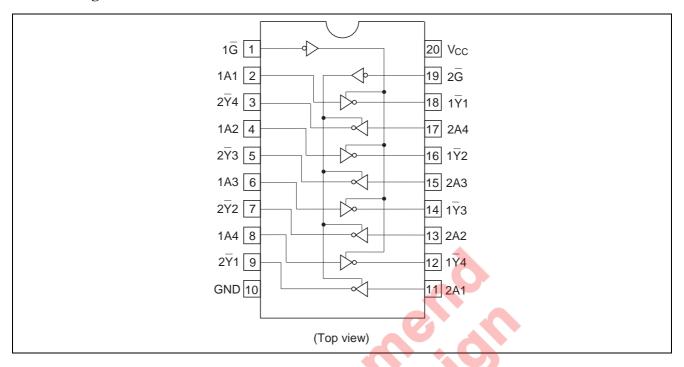
H: High level

L: Low level

X: Immaterial

Z: High impedance

## **Pin Arrangement**



## **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	Vcc	-0.5 to 6.0	V	
Input diode current	I <sub>IK</sub>	-50	mA	$V_1 = -0.5 \text{ V}$
Input voltage	VI	-0.5 to 6.0	V	
Output diode current	I <sub>OK</sub>	-50	mA	$V_{O} = -0.5 \text{ V}$
		50		$V_O = V_{CC} + 0.5 \text{ V}$
Output voltage	Vo	$-0.5$ to $V_{CC}$ +0.5	V	Output "H" or "L"
		-0.5 to 6.0	<del></del>	Output "Z" or V <sub>CC</sub> :OFF
Output current	I <sub>0</sub>	±50	mA	
V <sub>CC</sub> , GND current / pin	I <sub>CC</sub> or I <sub>GND</sub>	100	mA	
Storage temperature	Tstg	-65 to +150	°C	

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

## **Recommended Operating Conditions**

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V <sub>CC</sub>	1.5 to 5.5	V	Data hold
		2.0 to 5.5		At operation
Input / output voltage	Vı	0 to 5.5	V	G, A
	Vo	0 to V <sub>CC</sub>	V	Output "H" or "L"
		0 to 5.5		Output "Z" or V <sub>CC</sub> :OFF
Operating temperature	Та	-40 to 85	°C	
Output current	I <sub>OH</sub>	-12	mA	V <sub>CC</sub> = 2.7 V
		-24 <sup>*2</sup>		V <sub>CC</sub> = 3.0 V to 5.5 V
	I <sub>OL</sub>	12	mA	V <sub>CC</sub> = 2.7 V
		24 <sup>*2</sup>		V <sub>CC</sub> = 3.0 V to 5.5 V
Input rise / fall time *1	t <sub>r</sub> , t <sub>f</sub>	10	ns/V	

Notes: 1. This item guarantees maximum limit when one input switches.

Waveform: Refer to test circuit of switching characteristics.

2. Duty cycle ≤ 50%

## **Electrical Characteristics**

			Ta = -4	0 to 85°C		
Item	Symbol	V <sub>CC</sub> (V)	Min	Max	Unit	Test Conditions
Input voltage	V <sub>IH</sub>	2.7 to 3.6	2.0		V	
		4.5 to 5.5	V <sub>CC</sub> ×0.7			
	V <sub>IL</sub>	2.7 to 3.6	-	0.8	V	
		4.5 to 5.5	40	$V_{CC}\times0.3$		
Output voltage	$V_{OH}$	2.7 to 5.5	V <sub>CC</sub> -0.2	_	V	$I_{OH} = -100 \mu A$
		2.7	2.2	7	_	$I_{OH} = -12 \text{ mA}$
		3.0	2.4	_	_	
		3.0	2.2	_	_	$I_{OH} = -24 \text{ mA}$
		4.5	3.8	_		
	V <sub>OL</sub>	2.7 to 5.5	_	0.2	V	$I_{OL} = 100 \mu A$
	70	2.7	_	0.4	_	I <sub>OL</sub> = 12 mA
		3.0	_	0.55	_	$I_{OL} = 24 \text{ mA}$
	A 6	4.5	_	0.55		
Input current	I <sub>IN</sub>	0 to 5.5	_	±5.0	μΑ	$V_{IN} = 5.5 V_{CC}$ or GND
Off state output current	$I_{OZ}$	2.7 to 5.5	_	±5.0	μΑ	$V_{IN} = V_{CC}$ , GND
						$V_{OUT} = 5.5 \text{ V or GND}$
Output leak current	I <sub>OFF</sub>	0	_	20	μΑ	$V_{IN} / V_{OUT} = 5.5 V$
Quiescent supply current	I <sub>CC</sub>	2.7 to 3.6	_	±10	μΑ	$V_{IN} / V_{OUT} = 3.6 \text{ to } 5.5 \text{ V}$
		2.7 to 5.5	_	10		V <sub>IN</sub> = V <sub>CC</sub> or GND
	$\Delta I_{CC}$	3.0 to 3.6	_	500	μA	$V_{IN}$ = one input at $(V_{CC}-0.6)V$ ,
						other inputs at V <sub>CC</sub> or GND

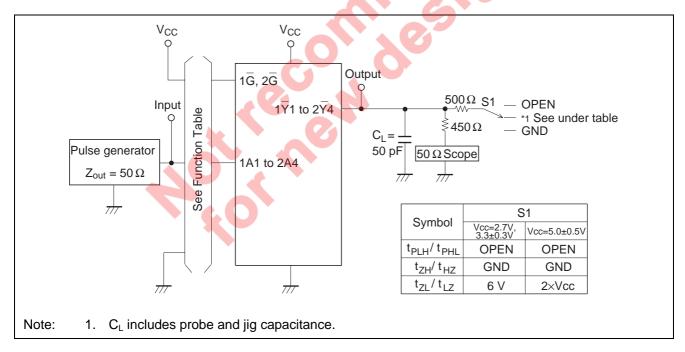
## **Switching Characteristics**

			Ta =	–40 to 85°C			From	То
Item	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Unit	(Input)	(Output)
Propagation delay time	t <sub>PLH</sub>	2.7	_	_	7.5	ns	А	Ÿ
	$t_{PHL}$	3.3±0.3	1.5	_	6.5			
		5.0±0.5	_	_	5.0			
Output enable time	t <sub>ZH</sub>	2.7	_	_	9.0	ns	G	Y
	$t_{ZL}$	3.3±0.3	1.5	_	8.0			
		5.0±0.5	_	_	6.5			
Output disable time	$t_{HZ}$	2.7	_	_	8.0	ns	G	Y
	$t_{LZ}$	3.3±0.3	1.5	_	7.0			
		5.0±0.5	_	_	6.0	<u></u>		
Between output pins skew	t <sub>OSLH</sub>	2.7	_	_	_	ns		
*1	$t_{OSHL}$	3.3±0.3	_	_	1.0			
		5.0±0.5	_	_	1.0			
Input capacitance	C <sub>IN</sub>	2.7	_	3.0	_	pF		
Output capacitance	Co	2.7	_	15.0	- 4	pF		

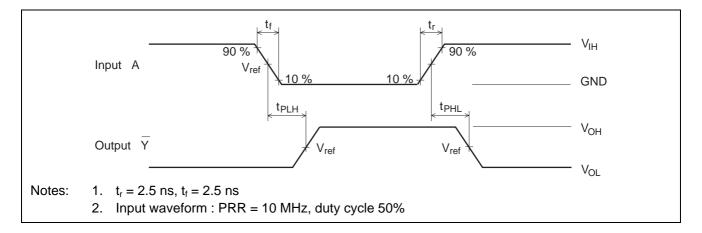
Note: 1. This parameter is characterized but not tested.

 $tos_{LH} = |\ t_{PLHm} \text{--}\ t_{PLHn}|,\ tos_{HL} = |\ t_{PHLm} \text{--}\ t_{PHLn}|$ 

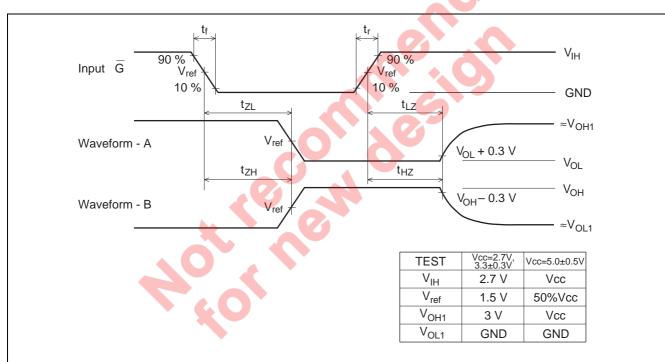
## **Test Circuit**



#### Waveforms-1



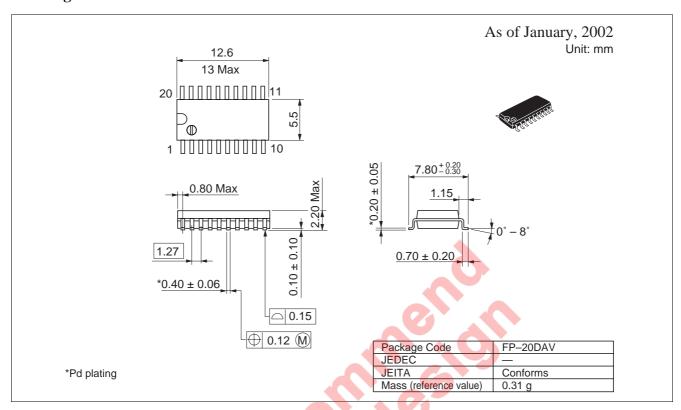
#### Waveforms - 2

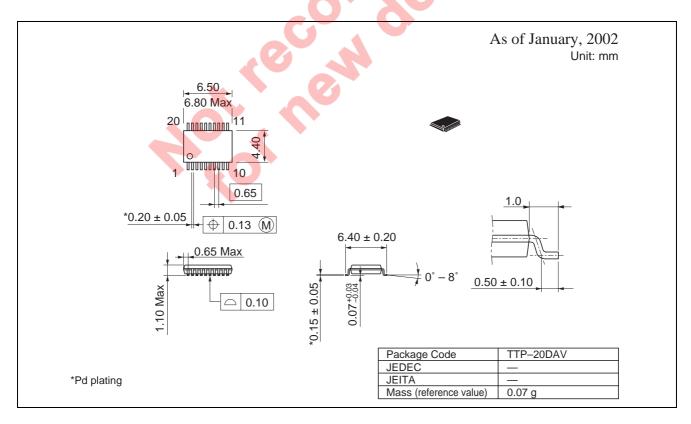


Notes:

- 1.  $t_r = 2.5 \text{ ns}, t_f = 2.5 \text{ ns}$
- 2. Input waveform: PRR = 10 MHz, duty cycle 50%
- 3. Waveform A shows input conditions such that the output is "L" level when enable by the output control.
- 4. Waveform B shows input conditions such that the output is "H" level when enable by the output control.

## **Package Dimensions**





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